

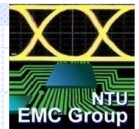
Microwave Filter Design

Chp6. Highpass Filters

Prof. Tzong-Lin Wu

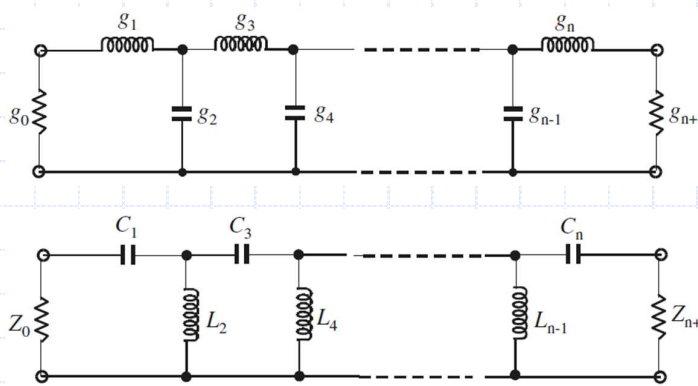
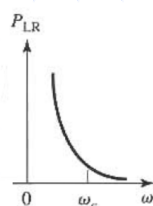
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Highpass Filters

➤ Highpass filter prototype



Highpass Transformation

$$\Omega = -\frac{\omega_c \Omega_c}{\omega}$$

$$C_i = \frac{1}{Z_0 \omega_c \Omega_c g_i} \quad L_i = \frac{Z_0}{\omega_c \Omega_c g_i}$$

- Find an appropriate microstrip realization
- ◆ Quasilumped HPF
 - ◆ Optimum Distributed HPF

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Example - Quasilumped Highpass Filters

➤ Design a three-order HPF with 0.1 dB ripple and cutoff frequency of 1.5 GHz. The source/load impedance of the filter is 50 Ω.

◆ Step 1 – Find out the required L/C element values

For passband ripple $L_{Ar} = 0.1$ dB

n	g_1	g_2	g_3	g_4	g_5	g_6
1	0.3052	1.0				
2	0.8431	0.6220	1.3554			
3	1.0316	1.1474	1.0316	1.0		
4	1.1088	1.3062	1.7704	0.8181	1.3554	
5	1.1468	1.3712	1.9750	1.3712	1.1468	1.0

$$C_1 = C_3 = \frac{1}{Z_0 \omega_c \Omega_c g_1} = \underline{2.0571 \times 10^{-12} \text{ F}}$$

$$L_2 = \frac{Z_0}{\omega_c \Omega_c g_2} = \underline{4.6236 \times 10^{-9} \text{ H}}$$

◆ Step 2 – Choose the adequate structures to implement the required L/C

▣ C1 and C3 are realized by interdigital capacitor

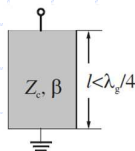


$$C(\text{pF}) = 3.937 \times 10^{-5} l(\epsilon_r + 1)[0.11(n - 3) + 0.252] \quad \text{for } l \text{ in } \mu\text{m}$$

or

Y-parameters from EM simulator

▣ L2 is realized by short-circuited stub

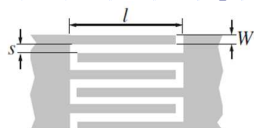


$$jZ_c \tan\left(\frac{2\pi}{\lambda_{gc}} l\right) = j\omega_c L_2$$

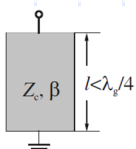
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Example - Stepped-impedance LPF

◆ Step 3 – find out the required physical length for element values

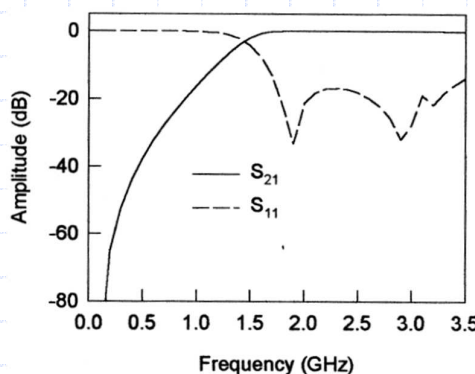
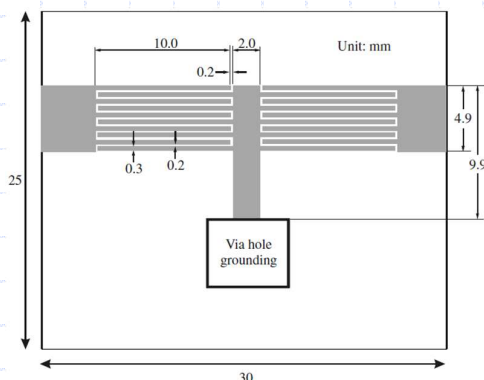


Number of fingers: 10
Length of fingers: 10 mm
Width of fingers: 0.3 mm
Space of fingers: 0.2 mm



Width of the line: 2 mm ($Z_c = 84.62 \Omega$)
Length of the line: 11.327 mm

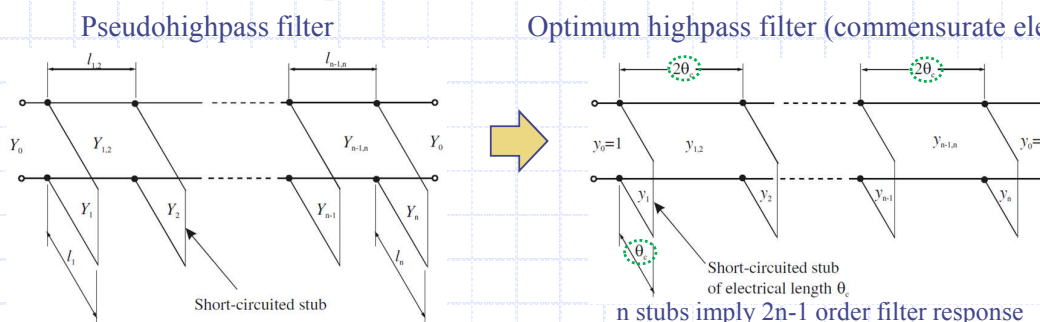
The microstrip is designed on a substrate with a dielectric constant of 2.2 and a thickness of 1.57 mm



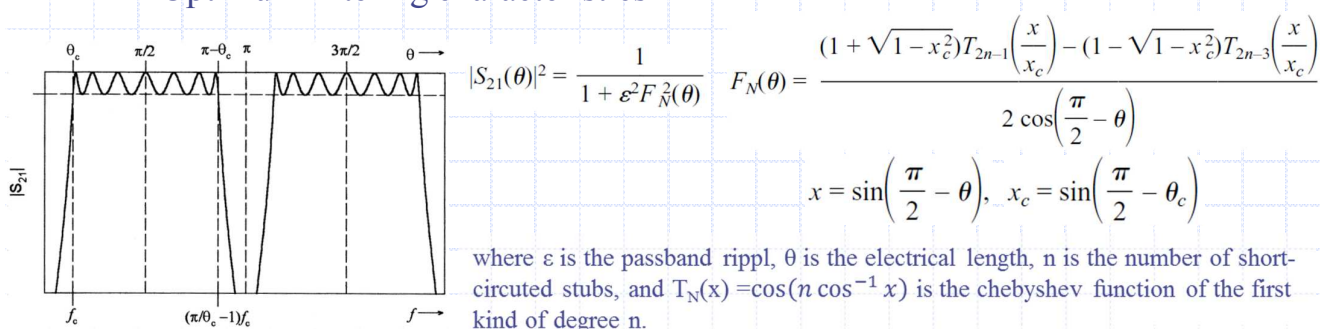
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Optimum Distributed Highpass Filters

➤ General structure – equal electrical length connecting line with shunting stubs



➤ Optimum filtering characteristics



Optimum Distributed Highpass Filters

➤ Design equations for optimum highpass filters

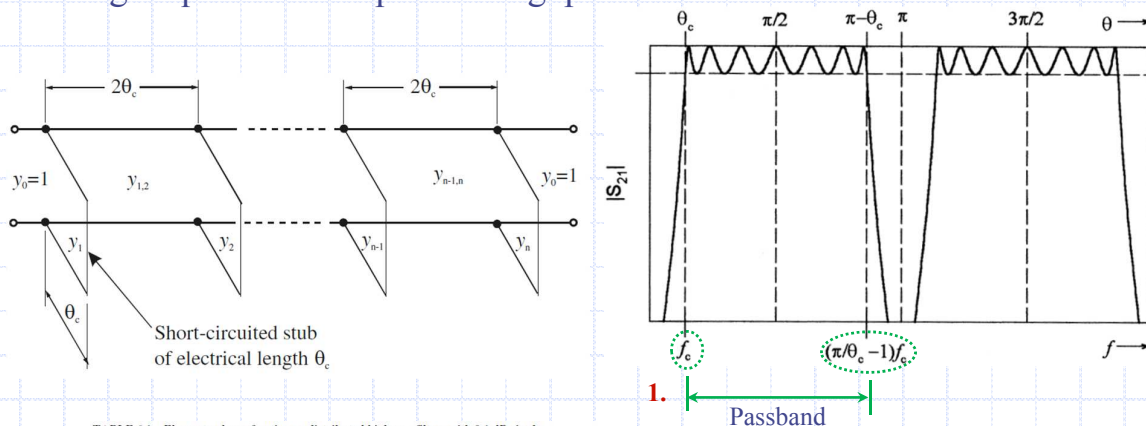


TABLE 6.1 Element values of optimum distributed highpass filters with 0.1 dB ripple

n	θ_c	y_1 y_n	$y_{1,2}$ $y_{n-1,n}$	y_2 y_{n-1}	$y_{2,3}$ $y_{n-2,n-1}$	y_3 y_{n-2}	$y_{3,4}$
2	25°	0.15436	1.13482				
	30°	0.22070	1.11597				
	35°	0.30755	1.08967				
3	25°	0.19690	1.12075	0.18176			
	30°	0.28620	1.09220	0.30726			
	35°	0.40104	1.05378	0.48294			
4	25°	0.22441	1.11113	0.23732	1.10361		
	30°	0.32300	1.07842	0.39443	1.06488		
	35°	0.44670	1.03622	0.60527	1.01536		
5	25°	0.24068	1.10540	0.27110	1.09317	0.29659	
	30°	0.34252	1.07119	0.43985	1.05095	0.48284	
	35°	0.46895	1.02790	0.66089	0.99884	0.72424	
6	25°	0.25038	1.10199	0.29073	1.08725	0.33031	1.08302
	30°	0.35346	1.06720	0.46383	1.04395	0.52615	1.03794
	35°	0.48096	1.02354	0.68833	0.99126	0.77546	0.98381

➤ Normalized characteristic admittance

2. Shorting stub: $Z_i = Z_0/y_i$

3. Connecting line: $Z_{i,i+1} = Z_0/y_{i,i+1}$

Example - Optimum Distributed Highpass Filters

- Design an optimum distributed HPF at cutoff frequency of 1.5 GHz and 0.1 dB ripple passband up to 6.5 GHz using 6 stubs. The source/load impedance of the filter is 50 Ω.

- ◆ Step 1 – Find out the required electrical length θ_c

$$\left(\frac{\pi}{\theta_c} - 1\right)f_c = 6.5 \quad \Rightarrow \quad \theta_c = 33.75^\circ$$

- ◆ Step 2 – look up table to find the required characteristic impedances of the element values

TABLE 6.1 Element values of optimum distributed highpass filters with 0.1 dB ripple

n	θ_c	y_1 y_n	$y_{1,2}$ $y_{n-1,n}$	y_2 y_{n-1}	$y_{2,3}$ $y_{n-2,n-1}$	y_3 y_{n-2}	$y_{3,4}$
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	30°	0.35346	1.06720	0.46383	1.04395	0.52615	1.03794
	35°	0.48096	1.02354	0.68833	0.99126	0.77546	0.98381

- Intepolation method to find $\theta_c = 33.75^\circ$

$$y_1 = 0.35346 + \frac{(0.48096 - 0.35346)}{5} \times 3.75$$

$$= 0.44909$$

$$y_{1,2} = 1.03446$$

$$y_2 = 0.63221$$

$$y_{2,3} = 1.00443$$

$$y_3 = 0.71313$$

$$y_{3,4} = 0.99734$$

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Example - Optimum Distributed Highpass Filters

- Find the characteristic impedances for the line elements ($Z_0 = 50$)

$$Z_1 = Z_6 = \frac{Z_0}{y_1} = \frac{Z_0}{y_6} = \frac{50}{0.44909} = 111.34 \Omega$$

$$Z_{1,2} = Z_{5,6} = \frac{Z_0}{y_{1,2}} = \frac{Z_0}{y_{5,6}} = \frac{50}{1.03446} = 48.33 \Omega$$

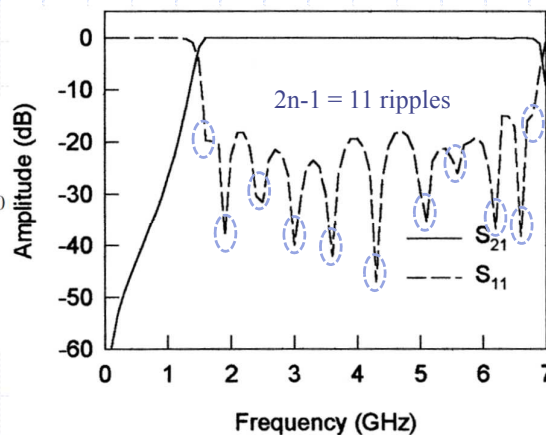
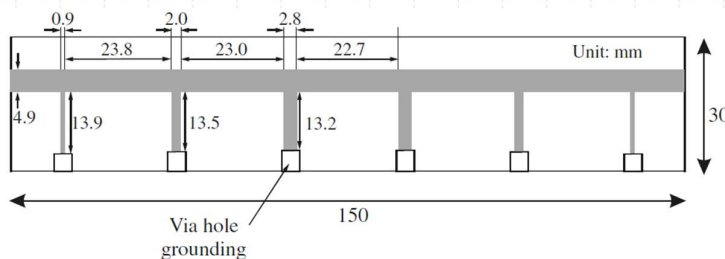
$$Z_2 = Z_5 = \frac{Z_0}{y_2} = \frac{Z_0}{y_5} = \frac{50}{0.63221} = 79.09 \Omega$$

$$Z_{2,3} = Z_{4,5} = \frac{Z_0}{y_{2,3}} = \frac{Z_0}{y_{4,5}} = \frac{50}{1.00443} = 49.78 \Omega$$

$$Z_3 = Z_4 = \frac{Z_0}{y_3} = \frac{Z_0}{y_4} = \frac{50}{0.71313} = 70.11 \Omega$$

$$Z_{3,4} = \frac{Z_0}{y_{3,4}} = \frac{50}{0.99734} = 50.13 \Omega$$

The microstrip is designed on a substrate with a dielectric constant of 2.2 and a thickness of 1.57 mm



HW V

Please design a HPF based on Butterworth prototype with the following specifications using interdigital capacitors and short-circuited stubs:

1. Cutoff frequency : 3 GHz
2. Insertion loss > 25 dB at 1 GHz

The properties of the substrate is $\epsilon_r = 4.4$ and loss tangent of 0. The substrate thickness is 1.6 mm.

- a. Please determine the order of the HPF.
- b. Find out the required series capacitances and shunt inductance.
- c. Plot the return loss and insertion loss for the designed HPF using ADS.
- d. Utilize 6, 8, and 10 fingers to realize this HPF and discuss the frequency response for the three structures in EM solver.
- e. Discuss the frequency responses from the circuit simulator (ADS) and EM solver.